

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Type CRGP Series

Key Features

Small size and light weight

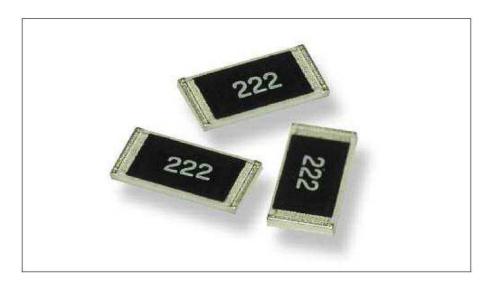
Suitable for both wave and reflow soldering techniques

Supplied on tape

Pulse Rated

7 different package sizes

Terminal finish matte Sn over Ni



TE Connectivity is pleased to introduce this SMD Pulse withstand thick film Chip resistor, suitable for auto placement in volume and for most applications. Available in five different packages and supplied on tape and reel for automatic insertion processes. Standard values — E24 Series

Characteristics - Electrical

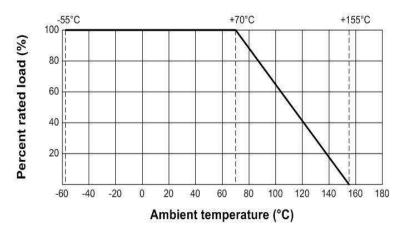
Туре	CRGP0402	CRGP0603	CRGP0805	CRGP1206		
Power Rating @ 70°C	0.125W	0.25W	0.33W	0.5W		
Max. Working Voltage	50V	50V	150V	200V		
Max. Overload Voltage	100V	100V	300V	400V		
Dielectric Withstand	100V	300V	500V	500V		
Temperature Range	-55°C ~ +155°C					
Ambient Temperature		•	70°C			

Туре	CRGP1210	CRGP2010	CRGP2512		
Power Rating @ 70°C	0.75W 1.25W		2W		
Max. Working Voltage	200V	400V	500V		
Max. Overload Voltage	500V	800V	1000V		
Dielectric Withstand	500V 500V 500V				
Temperature Range	-55°C ~ +155°C				
Ambient Temperature		70°C			

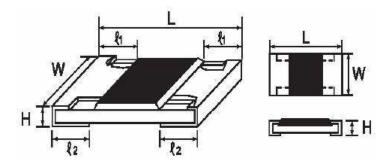


Power derating curve

Power rating based on continuous load operation in ambient temperature of 70°C. For resistors operated in ambient temperatures above 70°C, power rating must be derated in accordance with this curve.



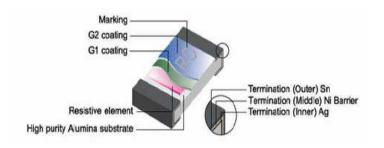
Dimensions:



Type		C	Dimension (mm	າ)	
Туре	L	W	Н	£1	€2
CRGP0402	1.10±0.10	0.50±0.05	0.35±0.05	0.20±0.10	0.25±0.10
CRGP0603	1.60±0.10	0.80±0.10	0.45±0.10	0.30±0.20	0.30±0.20
CRGP0805	2.00±0.15	1.25+0.15	0.55±0.10	0.40±0.20	0.40±0.20
		-0.10			
CRGP1206	3.10±0.15	1.55+0.15	0.55±0.10	0.45±0.20	0.45±0.20
		-0.10			
CRGP1210	3.10±0.10	2.60±0.20	0.55±0.10	0.55±0.25	0.50±0.20
CRGP2010	5.00±0.10	2.50±0.20	0.55±0.10	0.60±0.25	0.50±0.20
CRGP2512	6.35±0.10	3.20±0.20	0.55±0.10	0.60±0.25	0.50±0.20



Construction:



Power Rating and Resistance Range:

Туре	Power Rating	Tolerance	Resistance	Standard
	@ 70°C		Range	Series
		±1%		E24
CRGP0402	0.125W	±5%	1R0 – 10M	E96 by
				negotiation
		±1%		E24
CRGP0603	0.25W	±5%	1R0 – 10M	E96 by
				negotiation
		±1%		E24
CRGP0805	0.33W	±5%	1R0 – 10M	E96 by
				negotiation
		±1%		E24
CRGP1206	0.5W	±5%	1R0 – 10M	E96 by
				negotiation
		±1%		E24
CRGP1210	0.75W	±5%	1R0 – 10M	E96 by
				negotiation
		±1%		E24
CRGP2010	1.25W	±5%	1R0 – 10M	E96 by
				negotiation
		±1%		E24
CRGP2512	2W	±5%	1R0 – 10M	E96 by
				negotiation

Marking:

 $\rm E24~series~0603-2512~3~Digits-first~two~digits~denote~significant~figures~of~resistance~and~third~digit~denotes~number~of~zeros~thereafter.~EG$



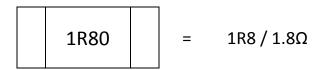


SMD Precision Pulse Thick Film Chip Resistor

Marking for E96 Series 0805 - 2512 4 digits – First three digits denote significant figures of resistance and fourth digit denotes number of zeros thereafter. EG.



For ohmic values below 100R letter "R" denotes decimal point. EG



0402 size chips are not marked

0603 E96 3 digit marking.

Mutiplier Code:

Code	A	В	C	D	E	F	G	H	X	Y	Z
	0	1	2	3	4	5	6	7	-1	-2	-3
Multiplier	10	10	10	10	10	10	10	10	10	10	10

Coding		Formula	Example:	10.2K Ω) =	102	X	10	Ω	=	02C
XX		X				02		č			
								-1			
8 in	Resistance Code	j.	Multiplier Code	33.2Ω	=33	332 51	Х	10 ↓ X	Ω	=	51X

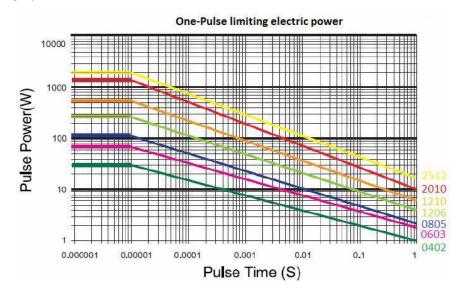
Value	Code								
100	01	162	21	261	41	422	61	681	81
102	02	165	22	267	42	432	62	698	82
105	03	169	23	274	43	442	63	715	83
107	04	174	24	280	44	453	64	732	84
110	05	178	25	287	45	464	65	750	85
113	06	182	26	294	46	475	66	768	86
115	07	187	27	301	47	487	67	787	87
118	08	191	28	309	48	499	68	806	88
121	09	196	29	316	49	511	69	825	89
124	10	200	30	324	50	523	70	845	90
127	11	205	31	332	51	536	71	866	91
130	12	210	32	340	52	549	72	887	92
133	13	215	33	348	53	562	73	909	93
137	14	221	34	357	54	576	74	931	94
140	15	226	35	365	55	590	75	953	95
143	16	232	36	374	56	604	76	976	96
147	17	237	37	383	57	619	77		
150	18	243	38	392	58	634	78		
154	19	249	39	402	59	649	79		
158	20	255	40	412	60	665	80		

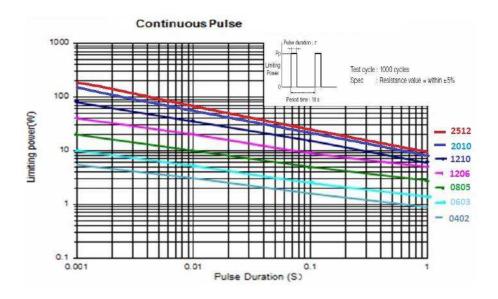


 Marking for E96 series 0603 size with no marking code marked as per E24 values.

Pulse withstand capacity

The single impulse graph is the result of 50 impulses of rectangular shape applied at one-minute intervals. The limit of acceptance was a shift in resistance of less than 1% from the initial value. The power applied was subject to the restrictions of the maximum permissible impulse voltage graph shown.







Performance Specification:

Characteristic	Limits	Test Methods
		(JIS C 5201-1)
Temperature	±100PPM/°C	Natural resistance change per temp.
Coefficient	*0402:	degree centigrade
	1Ω-10Ω : ± 400 PPM/°C	R1-R2
	11Ω-100Ω : ± 200 PPM/°C	x10 ⁶ (PPM/°C)
	>100Ω : ± 100 PPM/°C	R1(t2-t1)
		R1 resistance value at room temperature
		(t1)
		R2 Resistance value at room temperature
		+100°C (t2)
		(Sub-clause 4.8)
Short term	Resistance change rate is	Permanent resistance change after the
overload	$\pm 5\%$: ±(2.0% ±0.1Ω) Max.	application of a potential of 2.5 times
Overioau	$\pm 1\%$: $\pm (1.0\% \pm 0.1\Omega)$ Max.	RCWV for 5 seconds
	±1% . ±(1.0% ±0.112) IVIAX.	Sub-clause 4.13
Torminal	1 /1 09/ 10 0FO\ Ma	
Terminal	± (1.0% ±0.05Ω) Max.	Twist of Test Board:
Bending		Y/X = 5/90 mm for 10 seconds
	4 000149	(Sub-clause 4.33)
Insulation	1,000MΩ or more	Apply 500V DC between protective coating
Resistance		and termination for 1 min, then measure
		(Sub-clause 5.6)
Dielectric	No evidence of flashover,	Apply 500V AC between protective coating
Withstand	mechanical damage, arcing	and termination for 1 minute
Voltage	or insulation breakdown.	(Sub-clause 4.7)
Soldering Heat	Resistance change rate is	Dip the resistor into a solder bath having a
	±(1.0%+0.05Ω) Max.	temperature of 260°C±3°C and hold it for
		10±1 seconds
		(Sub-clause 4.18)
Solderability	95% coverage Min.	Test temperature of solder : 245 ± 3 °C
		Dwell time in solder: 2 ~ 3 seconds
		(Sub-clause 4.17)
Solder Temp.	Electrical characteristics	Wave soldering condition: (2 cycles Max.)
Reference	shall be satisfied without	Pre-heat : 100 ~ 120 °C, 30 ± 5 sec.
	distinct deformation in	Peak temp.: 260 °C
	appearance.	Reflow soldering condition: (2 cycles Max.)
	(95% coverage Min.)	Pre-heat: 150 ~ 180 °C, 90 ~ 120 sec.
		Suggestion solder temp.: 235 ~ 255 °C, 20 ~
		40 sec.
		Peak temp.: 260 °C
		(°C) Peak: 260°C (Max)
		250 235°C~255°C
		200
		180 °C Pre Heating Zone
		150 150 °C
		90 ~ 120 sec
		100 20~40 sec
		Soldering Zone
		50 Heading since
		Heating time
		Temperature profile for availuation Hand Soldering 300°C 5 seconds
		Tidina Soldering Soo e S Seconds

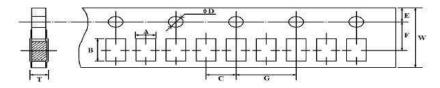


Performance Specification (continued)

Characteristic	Limits		Test Metho	ods			
			(JIS C 5201	-1)			
		Resistance change after continuous 5					
		cycles	for duty specified	below:			
	Dosistanco chango rato is:	Step	Temperature	Time			
Temperature	Resistance change rate is: ±5%: ±(3%±0.1Ω) Max.	1	-55°C±3°C	30 mins.			
Cycling	±3%. ±(5%±0.1Ω) Max. ±1%: ±(0.5%±0.1Ω) Max.	2	Room Temp.	10~15 mins.			
	±170. ±(0.570±0.152) Wax.	3	+155°C±2°C	30 mins.			
		4	Room Temp.	10~15 mins.			
		(Sub-c	lause 4.19)				
		Temp	orary resistance c	hange after			
	Resistance change rate is:	240 hours exposure in a humidity test					
Humidity	$\pm (3.0\% + 0.1\Omega)$ Max.	chaml	chamber controlled at 40±2°C and 90-				
	± (3.0% + 0.112) Wax.		95% relative humidity				
		(Sub-clause 4.24)					
Load Life In	Resistance change rate is:	Resistance change after 1,000 hours					
Humidity	$\pm 5\%$: $\pm (3.0\% \pm 0.1Ω)$ Max.	(1.5 hours "on", 0.5 hour "off") at					
	±1% : ±(1.0% ±0.1Ω) Max.	RCWV in a humidity chamber					
			olled at 40°C ± 2°C	and 90 to 95			
			tive humidity.				
1 11:6-	Basistana akaman metalia	.	clause 4.24.2.1)	L			
Load Life	Resistance change rate is:	Permanent resistance change after					
	$\pm 5\%$: $\pm (3.0\% \pm 0.1\Omega)$ Max.	1,000 hours operating at RCWV, with duty cycle of (1.5 hours "on", 0.5 hour					
	$\pm 1\%$: ±(1.0% ±0.1Ω) Max.	-					
		"off") at 70°C ± 2°C ambient (Sub-clause 4.25.1					
		(Sub-0	.iause 4.25.1				

Packaging Specification

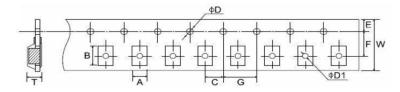
Paper taping



Туре	Α±	В±	C ±	ØD +0.1	Ε±	F±	G ±	W ±	Τ±
	0.2	0.2	0.05	-0	0.1	0.05	0.1	0.2	0.1
0402	0.65	1.15	2.0	1.5	1.75	3.5	4.0	8.0	0.45
0603	1.10	1.90	2.0	1.5	1.75	3.5	4.0	8.0	0.67
0805	1.65	2.40	2.0	1.5	1.75	3.5	4.0	8.0	0.81
1206	2.00	3.60	2.0	1.5	1.75	3.5	4.0	8.0	0.81
1210	2.80	3.50	2.0	1.5	1.75	3.5	4.0	8.0	0.75

SMD Precision Pulse Thick Film Chip Resistor

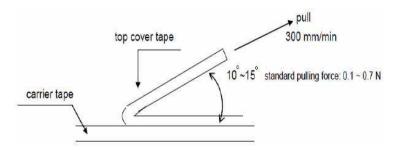
Embossed Taping



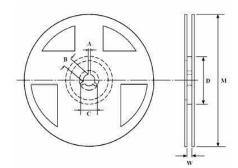
Туре	A ±0.2	B ±0.2	C ±0.05	ØD +0.1 -0	ØD1 +0.1 -0	E ±0.1	F ±0.05	G ±0.1	W ±0.2	T ± 0.1
2010	2.90	5.60	2.0	1.5	1.5	1.75	5.5	4.0	12.0	1.0
2512	3.50	6.70	2.0	1.5	1.5	1.75	5.5	4.0	12.0	1.0

Peeling strength of cover tape:

Test condition: 0.1 to 0.7 N at a peel off speed of 300mm / min.



Reel Dimensions (mm):



Туре	Tape	Reel	A ± 0.5	B ± 0.5	C ± 0.5	D ± 1	M ± 2	W ± 1
		Qty						
0402	Paper	10,000	2	13	21	60	178	10
0603	Paper	5,000	2	13	21	60	178	10
0805	Paper	5,000	2	13	21	60	178	10
1206	Paper	5,000	2	13	21	60	178	10
1210	Paper	5,000	2	13	21	60	178	10
2010	Embossed	4,000	2	13	21	60	178	13.8
2512	Embossed	4,000	2	13	21	60	178	13.8



SMD Precision Pulse Thick Film Chip Resistor

Label:

A. TE Product Number

B. Product Description

C. Quantity

D. Lot Number

E. RoHS Statement

Example:



Environment Related Substance

This product complies to EU RoHS directive, EU PAHs directive, EU PFOS directive and Halogen free.

Ozone layer depleting substances.

Ozone depleting substances are not used in our manufacturing process of this product.

This product is not manufactured using Chloro fluorocarbons (CFCs), Hydrochlorofluorocarbons (HCFCs), Hydrobromofluorocarbons (HBFCs) or other ozone depleting substances in any phase of the manufacturing process.

Storage Condition

The performance of these products, including the solderability, is guaranteed for a year from the date of arrival at your company, provided that they remain packed as they were when delivered and stored at a temperature of $25^{\circ}\text{C} \pm 10^{\circ}\text{C}$ and a relative humidity of $60^{\circ}\text{RH} \pm 10^{\circ}\text{RH}$, chemical and dust free atmosphere

Even within the above guarantee periods, do not store these products in the following conditions otherwise, their electrical performance and/or solderability may be deteriorated, and the packaging materials (e.g. taping materials) may be deformed or deteriorated, resulting in mounting failures.

1. In salty air or in air with a high concentration of corrosive gas, such as CI2, H2S, NH3, SO2, or NO2

2. In direct sunlight



Solder Profile

Wave soldering condition: (2 cycles Max.)

Pre-heat : $100 \sim 120 \, ^{\circ}\text{C}$, $30 \pm 5 \, \text{sec}$.

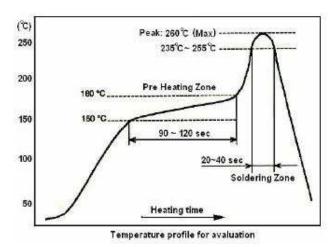
Peak temp.: 260 °C

Reflow soldering condition: (2 cycles Max.)

Pre-heat : 150 $^{\sim}$ 180 $^{\circ}$ C, 90 $^{\sim}$ 120 sec.

Suggestion solder temp.: 235 $^{\circ}$ 255 $^{\circ}$ C, 20 $^{\sim}$ 40 sec.

Peak temp.: 260 °C



Hand Soldering condition: The Soldering iron tip should be less than 300°C and maximum contact time should be 5 seconds

How To Order

CRGP	0603	J	10K
Common Part	Size	Tolerance	Resistance Value
CRGP – Pulse Withstand Thick Film Chip Resistor	0402 0603 0805 1206 1210 2010 2512	F - ±1% J - ±5%	1 ohm (1Ω) 1R0 1K ohm (1000Ω) 1K0 100K ohm (100000Ω) 100K 1M ohm (1000000Ω) 1M0